



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 2SB1124/2SD1624 — PNP/NPN Epitaxial Planar Silicon Transistors High Current Switching Applications

### Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment

### Features

- Adoption of FBET, MBIT processes
- Fast switching speed
- Low collector-to-emitter saturation voltage
- Large current capacity and wide ASO

### Specifications ( ) : 2SB1124

#### Absolute Maximum Ratings at Ta=25°C

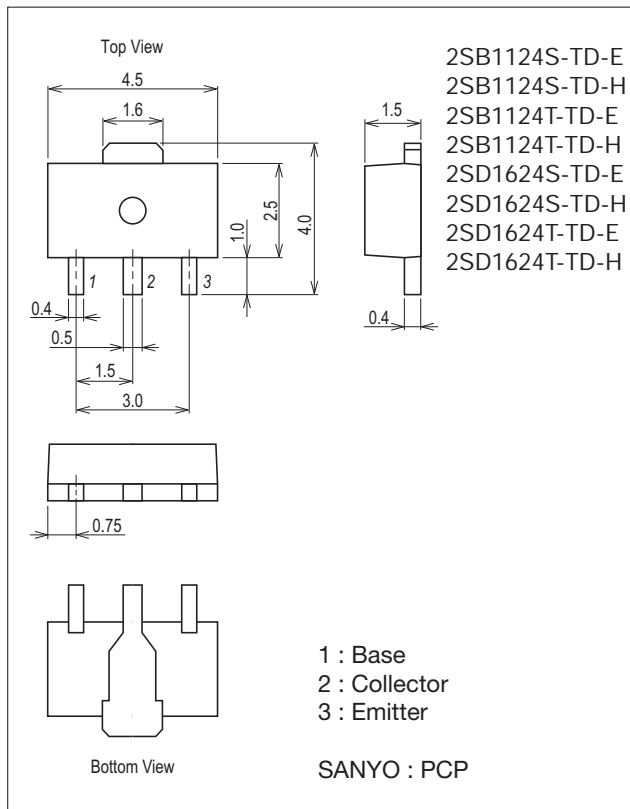
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		(-)60	V
Collector-to-Emitter Voltage	V <sub>CE0</sub>		(-)50	V
Emitter-to-Base Voltage	V <sub>EB0</sub>		(-)6	V
Collector Current	I <sub>C</sub>		(-)3	A
Collector Current (Pulse)	I <sub>CP</sub>		(-)6	A

Continued on next page.

### Package Dimensions

unit : mm (typ)

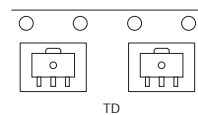
7007B-004



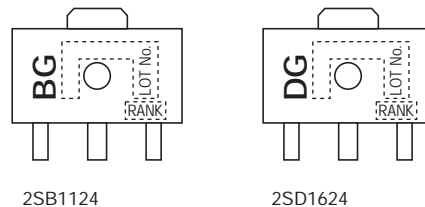
### Product & Package Information

- Package : PCP
- JEITA, JEDEC : SC-62, SOT-89, TO-243
- Minimum Packing Quantity : 1,000 pcs./reel

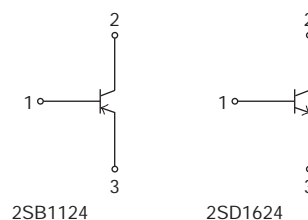
### Packing Type: TD



### Marking



### Electrical Connection



## 2SB1124/2SD1624

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		500	mW
		When mounted on ceramic substrate (250mm <sup>2</sup> ×0.8mm)	1.5	W
Junction Temperature	T <sub>j</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

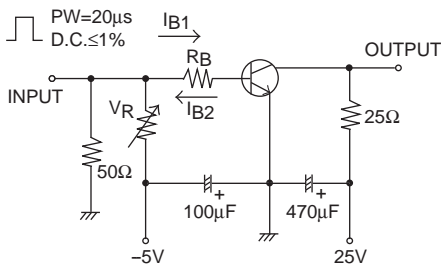
### Electrical Characteristics at T<sub>a</sub>=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0A			(-1)	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0A			(-1)	μA
DC Current Gain	h <sub>FE1</sub>	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)100mA	100*		560*	
	h <sub>FE2</sub>	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)3A	35			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		150		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(39)25		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)2A, I <sub>B</sub> =(-)100mA		(-0.35)0.19	(-0.7)0.5	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	V <sub>CE</sub> =(-)2A, I <sub>C</sub> =(-)100mA		(-0.94)	(-1.2)	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0A	(-60)			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-50)			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0A	(-6)			V
Turn-ON Time	t <sub>on</sub>	See specified Test Circuit.		(70)70		ns
Storage Time	t <sub>stg</sub>			(450)650		ns
Fall Time	t <sub>f</sub>			(35)35		ns

\* ; The 2SB1124/2SD1624 are classified by 100mA h<sub>FE</sub> as follows :

Rank	R	S	T	U
h <sub>FE</sub>	100 to 200	140 to 280	200 to 400	280 to 560

### Switching Time Test Circuit

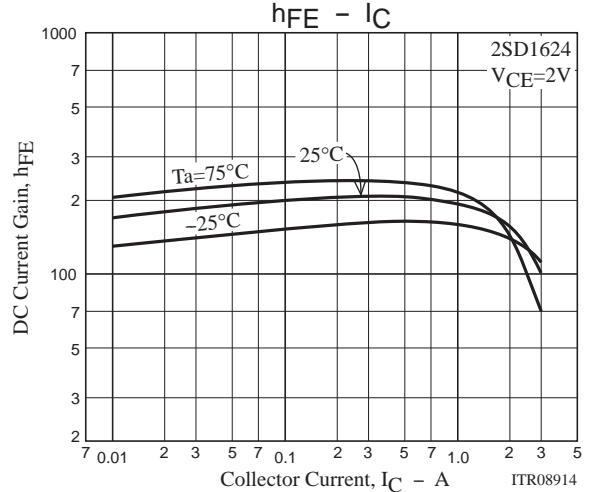
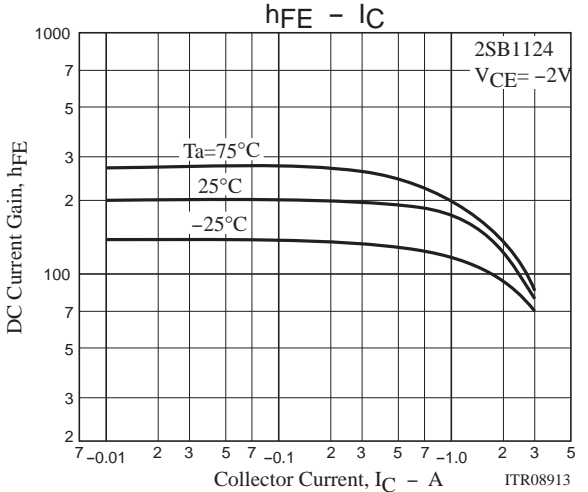
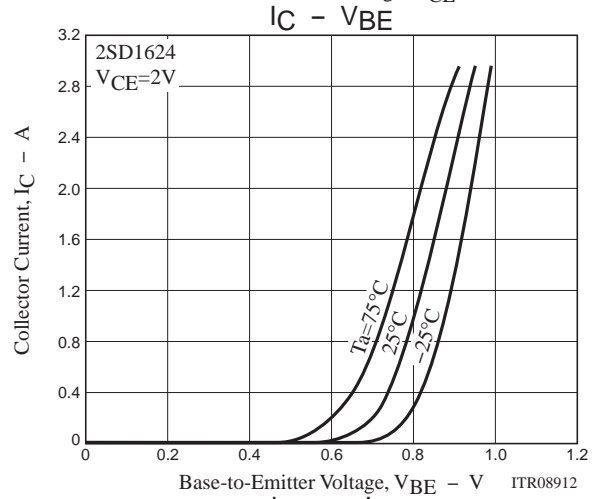
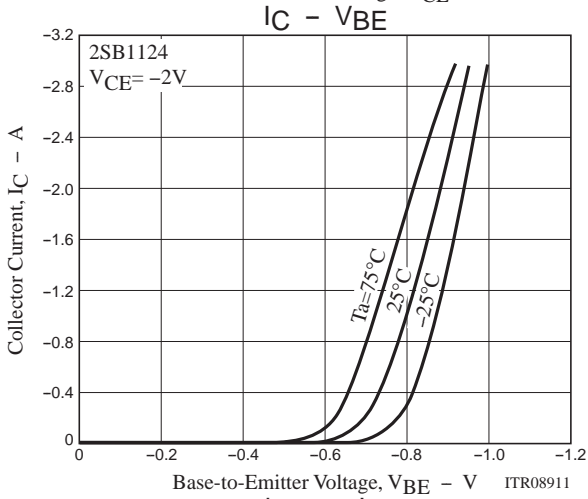
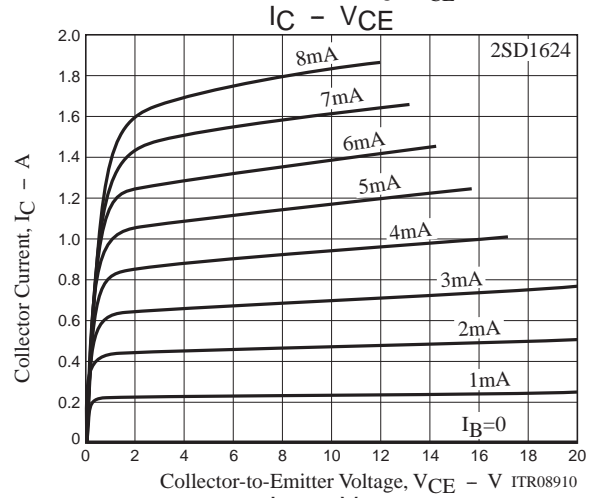
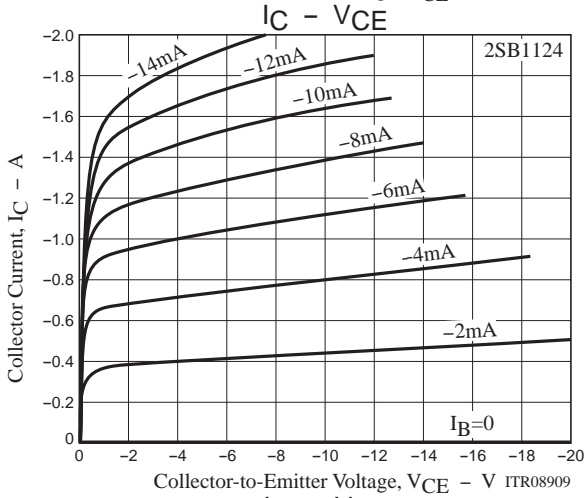
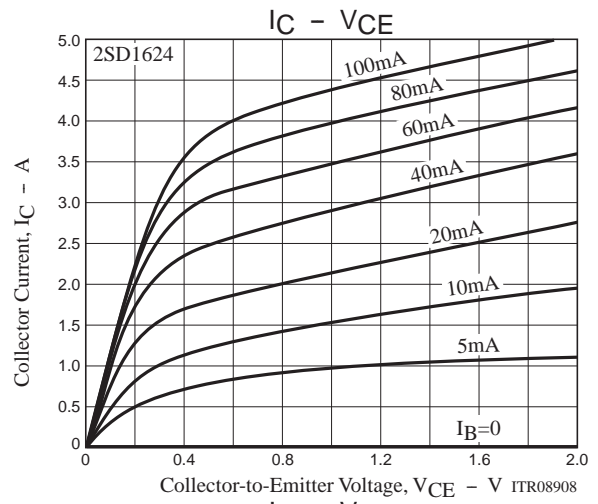
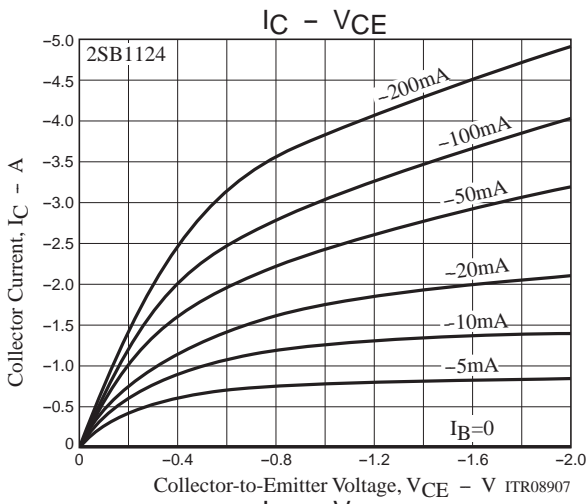


$$I_C = 10I_{B1} = -10I_{B2} = 1A$$

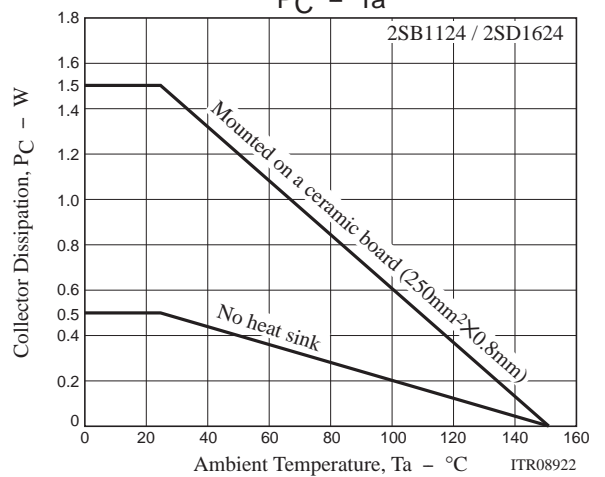
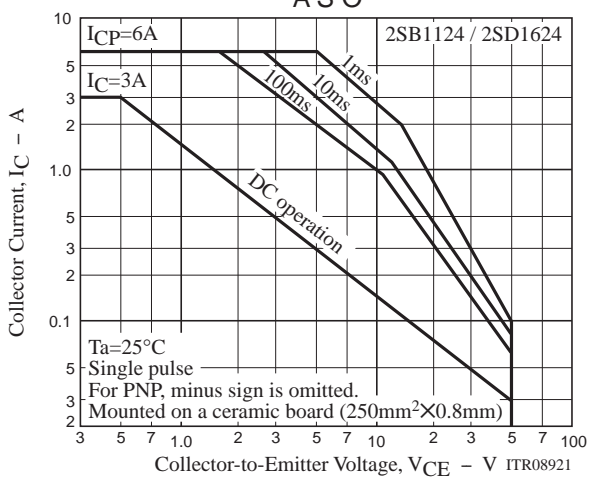
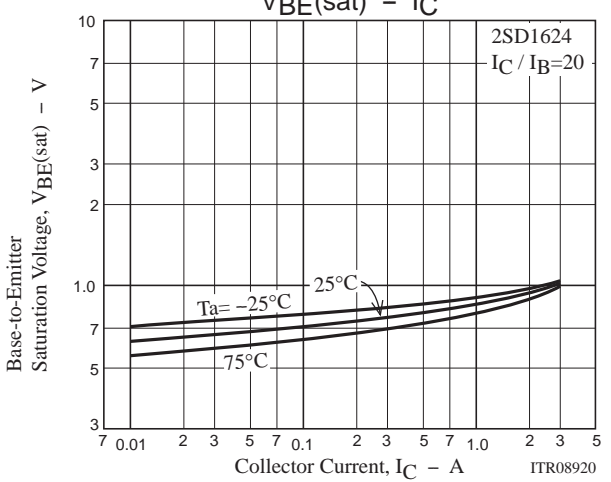
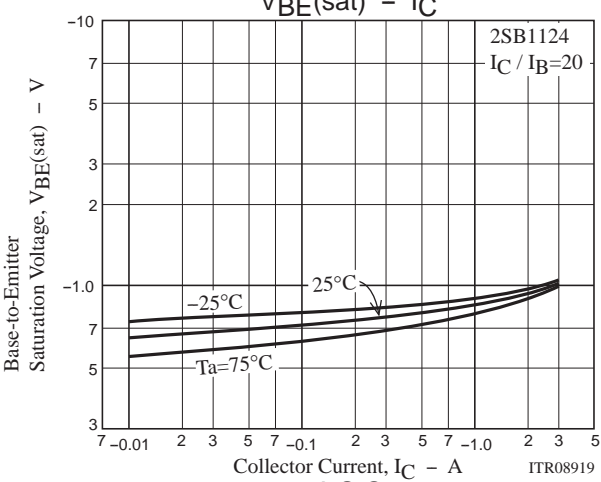
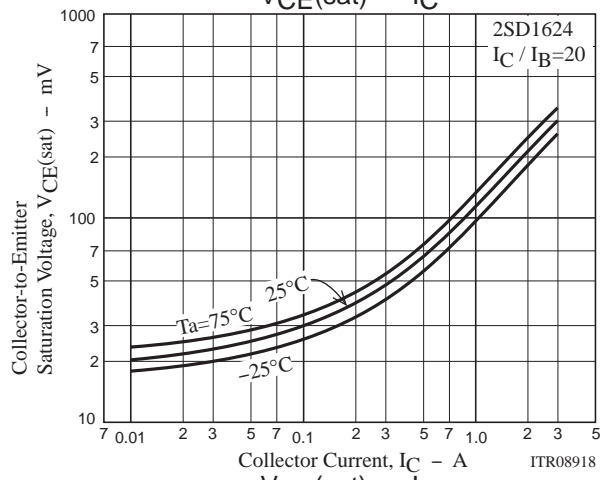
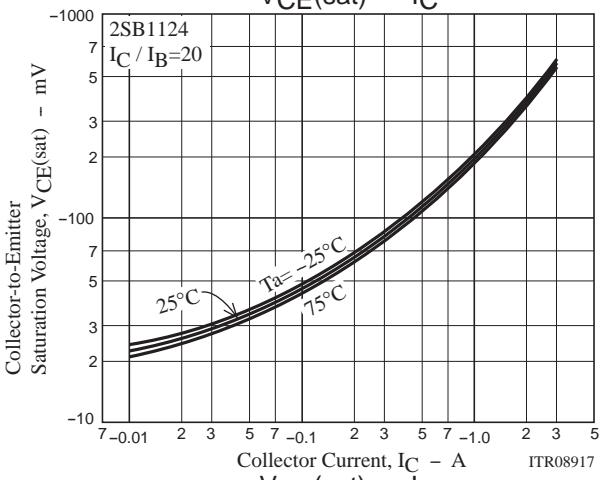
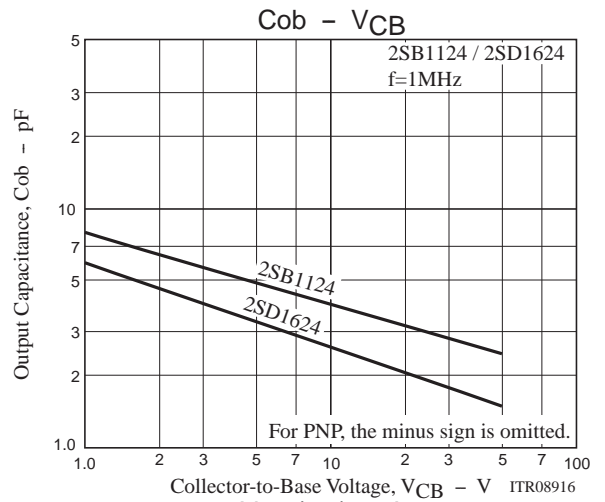
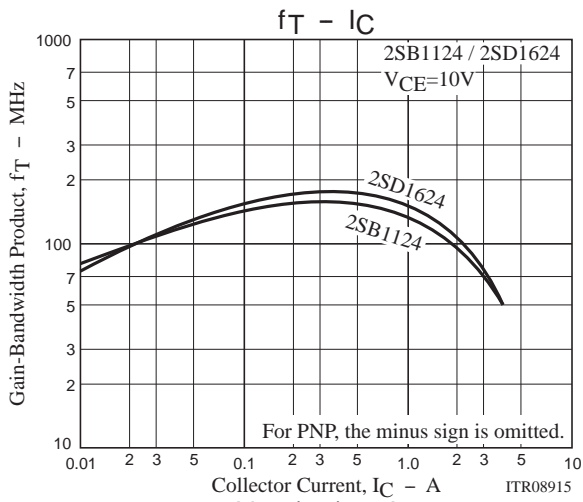
For PNP, the polarity is reversed.

### Ordering Information

Device	Package	Shipping	memo
2SB1124S-TD-E	PCP	1,00pcs./reel	Pb Free
2SB1124S-TD-H	PCP	1,00pcs./reel	Pb Free and Halogen Free
2SB1124T-TD-E	PCP	1,00pcs./reel	Pb Free
2SB1124T-TD-H	PCP	1,00pcs./reel	Pb Free and Halogen Free
2SD1624S-TD-E	PCP	1,00pcs./reel	Pb Free
2SD1624S-TD-H	PCP	1,00pcs./reel	Pb Free and Halogen Free
2SD1624T-TD-E	PCP	1,00pcs./reel	Pb Free
2SD1624T-TD-H	PCP	1,00pcs./reel	Pb Free and Halogen Free



# 2SB1124/2SD1624



# 2SB1124/2SD1624

## Bag Packing Specification

2SB1124S-TD-E, 2SB1124S-TD-H, 2SB1124T-TD-E, 2SB1124T-TD-H, 2SD1624S-TD-E, 2SD1624S-TD-H, 2SD1624T-TD-E, 2SD1624T-TD-H

### 1. Packing Format

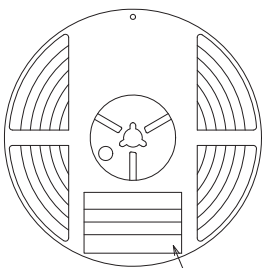
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1,000	4,000	24,000	4 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit: mm)

Outer box label

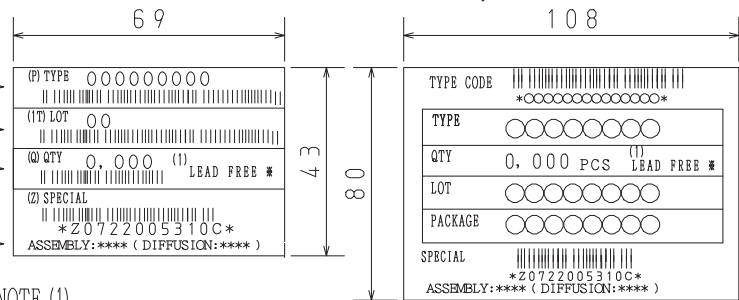
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

#### Packing method



Type No.  
LOT No.  
Quantity  
Origin

Reel label



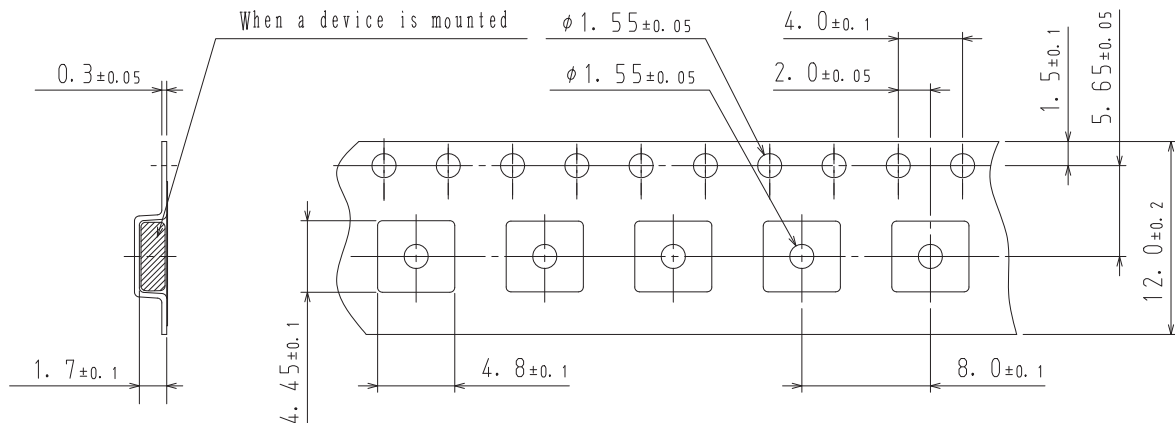
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

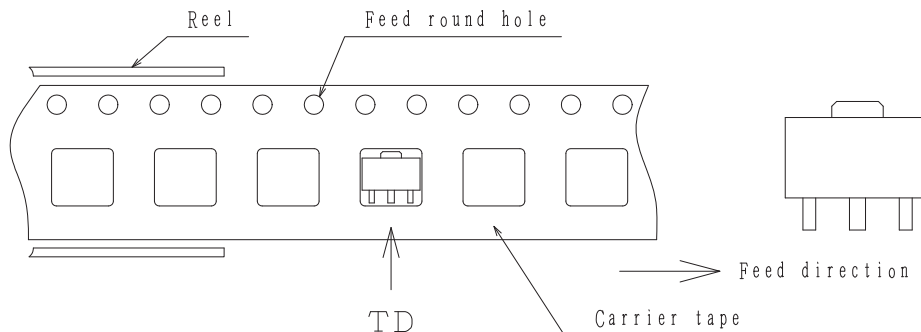
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

### 2. Taping configuration

#### 2-1. Carrier tape size (unit:mm)



#### 2-2. Device placement direction

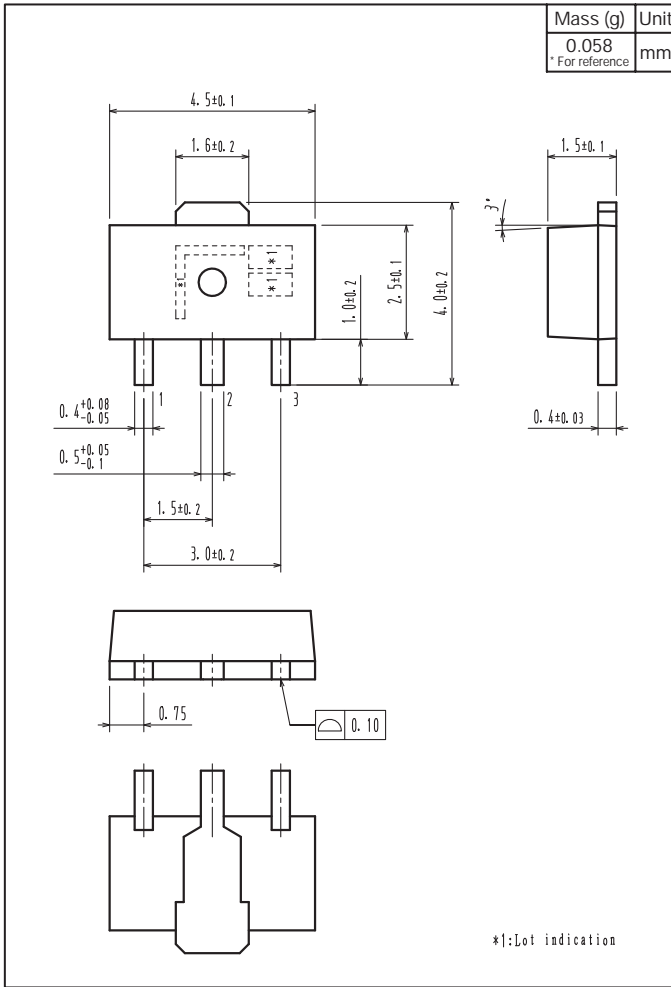


Those with pin 1 index on the feed hole side.....TD

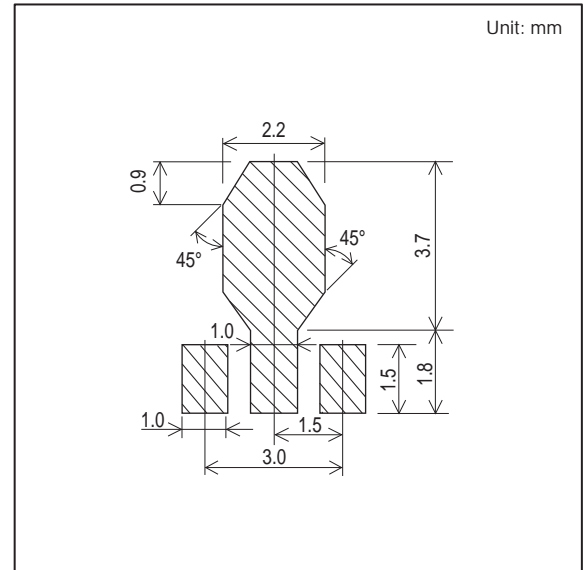
# 2SB1124/2SD1624

## Outline Drawing

2SB1124S-TD-E, 2SB1124S-TD-H, 2SB1124T-TD-E, 2SB1124T-TD-H, 2SD1624S-TD-E, 2SD1624S-TD-H, 2SD1624T-TD-E, 2SD1624T-TD-H



## Land Pattern Example



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